

SN74AHCT1G08 单通道双输入正与门

1 特性

- 工作范围：4.5V 至 5.5V
- 5V 时 t_{pd} 最大值为 7.1ns
- 低功耗： I_{CC} 最大值为 10 μ A
- 5V 时，输出驱动为 ± 8 mA
- 输入兼容 TTL 电压
- 闩锁性能超过 250mA，符合 JESD 17 规范

2 应用

- 电视、机顶盒和音频
- 无线基础设施
- 工厂自动化与控制
- PC 和笔记本电脑
- 楼宇自动化
- 电网基础设施
- 医疗、保健与健身
- 打印机
- 测试和测量
- EPOS (电子销售终端)
- 电信基础设施
- 投影仪

3 说明

SN74AHCT1G08 器件是一个单通道双输入正与门。该器件以正逻辑执行布尔函数 $Y = A \times B$ or $Y = \overline{A + B}$ 。该器件具有低 I_{CC} 电流，可用于功耗敏感型或电池供电型应用。

封装信息

器件型号	封装 ⁽¹⁾	封装尺寸 ⁽²⁾	封装尺寸 ⁽³⁾
SN74AHCT1G08	DBV (SOT-23 , 5)	2.9mm × 2.8mm	2.9mm × 1.6mm
	DCK (SC70 , 5)	2.00mm × 1.25mm	2.00mm × 1.25mm
	DRL (SOT , 5)	1.60mm × 1.6mm	1.60mm × 1.2mm

- 如需了解所有可用封装，请参阅数据表末尾的可订购产品附录。
- 封装尺寸 (长 × 宽) 为标称值，并包括引脚 (如适用)。
- 封装尺寸 (长 × 宽) 为标称值，不包括引脚。

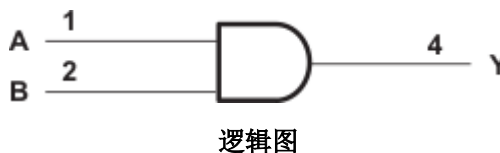


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4 Pin Configuration and Functions

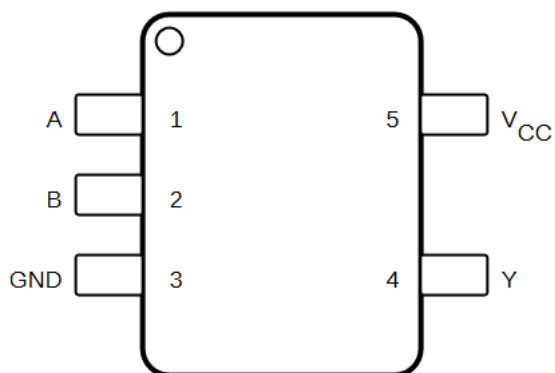


图 4-1. DBV, DCK, and DRL Packages 5-Pin SOT-23, SC70, and SOT (Top View)

PIN		TYPE ⁽¹⁾	DESCRIPTION
NAME	NO.		
A	1	I	Input A
B	2	I	Input B
GND	3	—	Ground Pin
V _{CC}	5	—	Supply Pin
Y	4	O	Output

(1) Signal Types: I = Input, O = Output, I/O = Input or Output

5 Specifications

5.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted).⁽¹⁾

		MIN	MAX	UNIT
V_{CC}	Supply voltage	- 0.5	7	V
V_I	Input voltage ⁽²⁾	- 0.5	7	V
V_O	Output voltage ⁽²⁾	- 0.5	$V_{CC} + 0.5$	V
I_{IK}	Input clamp current	$V_I < 0$	- 20	mA
I_{OK}	Output clamp current	$V_O < 0$ or $V_O > V_{CC}$	± 20	mA
I_O	Continuous output current	$V_O = 0$ to V_{CC}	± 25	mA
	Continuous current through V_{CC} or GND		± 50	mA
T_J	Maximum junction temperature		150	°C
T_{stg}	Storage temperature	- 65	150	°C

- (1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under [# 5.3](#). Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

5.2 ESD Ratings

		VALUE	UNIT
$V_{(ESD)}$	Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾	± 2500
		Charged-device model (CDM), per JEDEC specification JESD22-C101 ⁽²⁾	± 1000

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
- (2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

5.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted).⁽¹⁾

		MIN	MAX	UNIT
V_{CC}	Supply voltage	4.5	5.5	V
V_{IH}	High-level input voltage	2		V
V_{IL}	Low-level input voltage		0.8	V
V_I	Input voltage	0	5.5	V
V_O	Output voltage	0	V_{CC}	V
I_{OH}	High-level output current		- 8	mA
I_{OL}	Low-level output current		8	mA
$\Delta t / \Delta v$	Input transition rise and fall rate		20	ns/V
T_A	Operating free-air temperature	- 40	125	°C

- (1) All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. See TI application report, *Implications of Slow or Floating CMOS Inputs* ([SCBA004](#)).

5.4 Thermal Information

THERMAL METRIC ⁽¹⁾		SN74AHCT1G08			UNIT
		DBV (SOT-23)	DCK (SC70)	DRL (SOT)	
		5 PINS	5 PINS	5 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	278	289.2	242.9	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	180.5	205.8	77.5	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	184.4	176.2	77.5	°C/W
ψ_{JT}	Junction-to-top characterization parameter	115.4	117.6	9.6	°C/W
ψ_{JB}	Junction-to-board characterization parameter	183.4	175.1	77.3	°C/W
$R_{\theta JC(bot)}$	Junction-to-case (bot) thermal resistance	N/A	N/A	N/A	°C/W

(1) For more information about traditional and new thermal metrics, see the *Semiconductor and IC Package Thermal Metrics* application report, [SPRA953](#).

5.5 Electrical Characteristics

over operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS		MIN	TYP	MAX	UNIT
V_{OH} High-level output voltage	$I_{OH} = -50 \mu A, V_{CC} = 4.5 V$	$T_A = 25^\circ C$	4.4	4.5		V
		$T_A = -40^\circ C \text{ to } 125^\circ C$	4.4			
	$I_{OH} = -8 mA, V_{CC} = 4.5 V$	$T_A = 25^\circ C$	3.94			
		$T_A = -40^\circ C \text{ to } 125^\circ C$	3.8			
V_{OL} Low-level output voltage	$I_{OL} = 50 \mu A, V_{CC} = 4.5 V$				0.1	V
	$I_{OL} = 8 mA, V_{CC} = 4.5 V$	$T_A = 25^\circ C$			0.36	
		$T_A = -40^\circ C \text{ to } 125^\circ C$			0.44	
I_I Input current	$V_I = 5.5 V \text{ or } GND, V_{CC} = 0 V \text{ to } 5.5 V$	$T_A = 25^\circ C$			± 0.1	μA
		$T_A = -40^\circ C \text{ to } 125^\circ C$			± 1	
I_{CC} Supply current	$V_I = V_{CC} \text{ or } GND, I_O = 0, V_{CC} = 5.5 V$	$T_A = 25^\circ C$			1	μA
		$T_A = -40^\circ C \text{ to } 125^\circ C$			10	
$\Delta I_{CC}^{(1)}$ Change in supply current	One input at 3.4 V, Other Inputs at V_{CC} or GND, $V_{CC} = 5.5 V$	$T_A = 25^\circ C$			1.35	mA
		$T_A = -40^\circ C \text{ to } 125^\circ C$			1.5	
C_i Input capacitance	$V_I = V_{CC} \text{ or } GND, V_{CC} = 5 V$			4	10	pF

(1) This is the increase in supply current for each input at one of the specified TTL voltage levels, rather than 0 V or V_{CC} .

5.6 Switching Characteristics

over recommended operating free-air temperature range, $V_{CC} = 5\text{ V} \pm 0.5\text{ V}$ (unless otherwise noted) (see [Load Circuit and Voltage Waveforms](#))

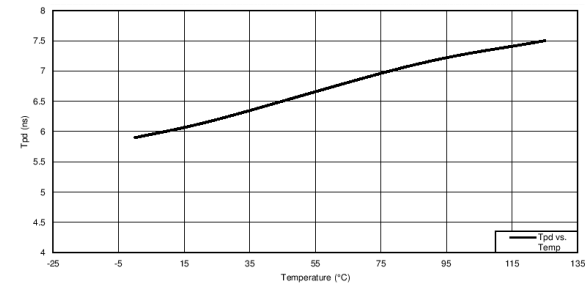
PARAMETER	FROM (INPUT)	TO (OUTPUT)	OUTPUT CAPACITANCE	TEST CONDITIONS	MIN	TYP	MAX	UNIT
t_{PLH} Propagation delay, low to high transition	A or B	Y	$C_L = 15\text{ pF}$	$T_A = 25^\circ\text{C}$		5	6.2	ns
				$T_A = -40^\circ\text{C to } 85^\circ\text{C}$	1		7.1	
				$T_A = -40^\circ\text{C to } 125^\circ\text{C}$	1		7.5	
t_{PHL} Propagation delay, high to low transition	A or B	Y	$C_L = 15\text{ pF}$	$T_A = 25^\circ\text{C}$		5	6.2	ns
				$T_A = -40^\circ\text{C to } 85^\circ\text{C}$	1		7.1	
				$T_A = -40^\circ\text{C to } 125^\circ\text{C}$	1		7.5	
t_{PLH} Propagation delay, low to high transition	A or B	Y	$C_L = 50\text{ pF}$	$T_A = 25^\circ\text{C}$		5.5	7.9	ns
				Propagation delay, high to low transition	1		9	
				$T_A = -40^\circ\text{C to } 125^\circ\text{C}$	1		10	
t_{PHL} Propagation delay, high to low transition	A or B	Y	$C_L = 50\text{ pF}$	$T_A = 25^\circ\text{C}$		5.5	7.9	ns
				$T_A = -40^\circ\text{C to } 85^\circ\text{C}$	1		9	
				$T_A = -40^\circ\text{C to } 125^\circ\text{C}$	1		10	

5.7 Operating Characteristics

$V_{CC} = 5\text{ V}$, $T_A = 25^\circ\text{C}$

PARAMETER	TEST CONDITIONS	TYP	UNIT
C_{pd} Power dissipation capacitance	No load, $f = 1\text{ MHz}$	18	pF

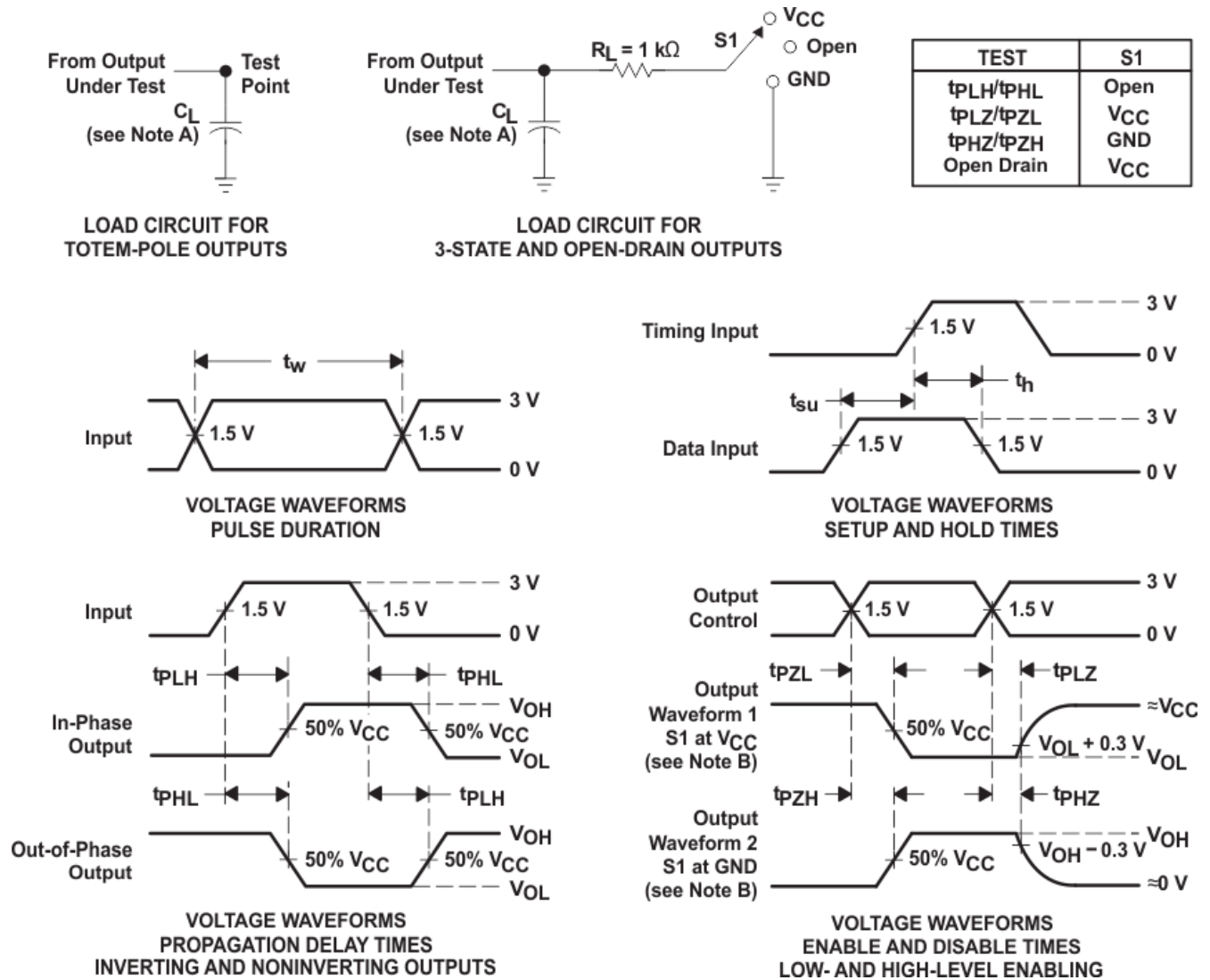
5.8 Typical Characteristics



$C_L = 15\text{ pF}$

图 5-1. T_{pd} vs Temperature

6 Parameter Measurement Information



C_L includes probe and jig capacitance.

Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control.

Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.

All input pulses are supplied by generators having the following characteristics: $PRR \leq 1\text{ MHz}$, $Z_O = 50\ \Omega$, $t_r \leq 3\text{ ns}$, $t_f \leq 3\text{ ns}$.

The outputs are measured one at a time with one input transition per measurement.

All parameters and waveforms are not applicable to all devices.

图 6-1. Load Circuit and Voltage Waveforms

7 Detailed Description

7.1 Overview

The SN74AHCT1G08 device is a single 2-input positive-AND gate. The device performs the Boolean AND function ($Y = A \cdot B$ or $Y = \overline{A + B}$) in positive logic. Low I_{CC} current allows this device to be used in power-sensitive or battery-powered applications. Robust inputs allow the device to up-translate with a propagation delay of 20 ns.

7.2 Functional Block Diagram



图 7-1. Logic Diagram (Positive Logic)

7.3 Feature Description

The V_{CC} for the device is optimized at 5 V.
Up voltage translation from 3.3 V to 5 V is allowed. The inputs accept V_{IH} levels of 2 V.
Output ringing is minimized by slow edge rates.
Inputs are TTL-Voltage compatible.

7.4 Device Functional Modes

表 7-1 lists the functional modes of the SN74AHCT1G08.

表 7-1. Function Table

INPUTS ⁽¹⁾		OUTPUT ⁽²⁾
A	B	Y
H	H	H
L	X	L
X	L	L

- (1) H = High Voltage Level, L = Low Voltage Level, X = Don't Care
- (2) H = Driving High, L = Driving Low, Z = High Impedance State

8 Application and Implementation

备注

以下应用部分中的信息不属于 TI 器件规格的范围，TI 不担保其准确性和完整性。TI 的客户应负责确定器件是否适用于其应用。客户应验证并测试其设计，以确保系统功能。

8.1 Application Information

The SN74AHCT1G08 device is a single AND gate, which is often used for many common functions like power sequencing or an *on* LED indicator. Because the device is configured to output LOW unless all inputs are HIGH, an LED tied to the output of the device will only turn HIGH when all systems connected are sending a HIGH, or *ready* signal.

8.2 Typical Application

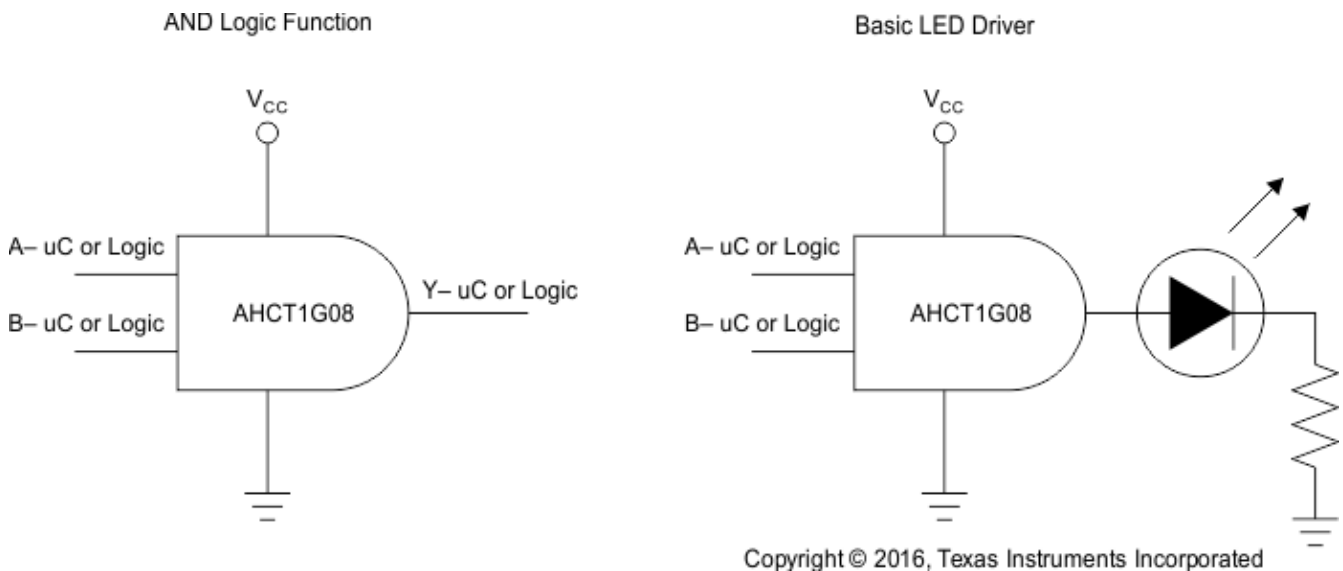


图 8-1. Typical Application Diagram

8.2.1 Design Requirements

This device uses CMOS technology and has balanced output drive. Take care to avoid bus contention because it can drive currents that would exceed maximum limits. The high drive also creates fast edges into light loads, so routing and load conditions must be considered to prevent ringing.

8.2.2 Detailed Design Procedure

1. Recommended Input Conditions
 - For rise time and fall time specifications, see $\Delta t / \Delta V$ in [节 5.3](#).
 - For specified high and low levels, see V_{IH} and V_{IL} in [节 5.3](#).
 - Inputs are overvoltage tolerant allowing them to go as high as 5.5 V at any valid V_{CC} .
2. Recommended Output Conditions
 - Load currents must not exceed 25 mA per output and 50 mA total for the part.
 - Outputs must not be pulled above V_{CC} .

8.2.3 Application Curve

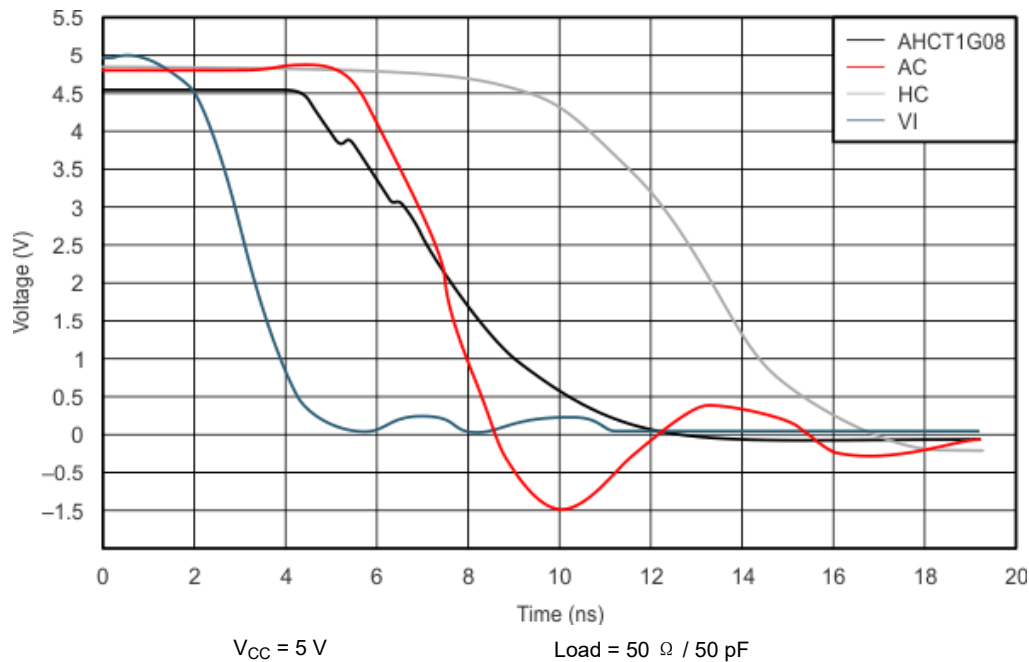


图 8-2. Typical Switching Characteristics

8.3 Power Supply Recommendations

The power supply can be any voltage between the minimum and maximum supply voltage rating located in [Recommended Operating Conditions](#).

Each V_{CC} pin must have a good bypass capacitor to prevent power disturbance. TI recommends a 0.1- μF capacitor for devices with a single supply; and a 0.01- μF or 0.022- μF capacitor for each power pin if there are multiple V_{CC} pins. It is ok to parallel multiple bypass capacitors to reject different frequencies of noise. 0.1- μF and 1- μF capacitors are commonly used in parallel. The bypass capacitor must be installed as close to the power pin as possible for best results.

8.4 Layout

8.4.1 Layout Guidelines

When using multiple bit logic devices inputs must not ever float. In many cases, functions or parts of functions of digital logic devices are unused; for example, when only two inputs of a triple-input AND gate are used or only 3 of the 4 buffer gates are used. Such input pins must not be left unconnected because the undefined voltages at the outside connections result in undefined operational states. Observe the following rules under all circumstances.

- All unused inputs of digital logic devices must be connected to a high or low bias to prevent them from floating.
- The logic level that must be applied to any particular unused input depends on the function of the device. Generally they will be tied to GND or V_{CC} , whichever make more sense or is more convenient.

8.4.1.1 Layout Example

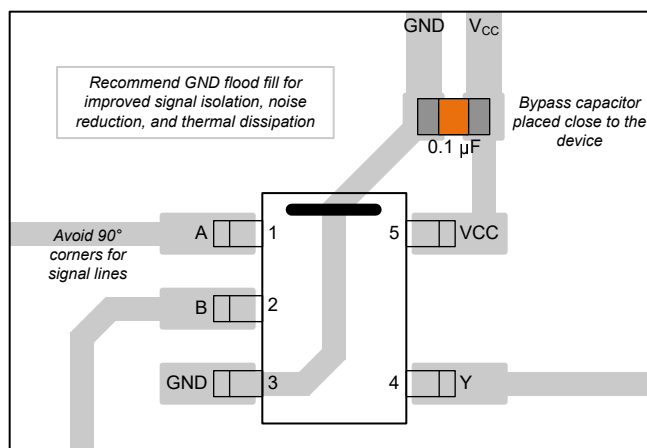


图 8-3. Layout Example for the SN74AHCT1G08

9 Device and Documentation Support

9.1 Documentation Support (Analog)

9.1.1 Related Documentation

For related documentation, see the following:

Implications of Slow or Floating CMOS Inputs, [SCBA004](#)

9.2 支持资源

[TI E2E™ 中文支持论坛](#) 是工程师的重要参考资料，可直接从专家处获得快速、经过验证的解答和设计帮助。搜索现有解答或提出自己的问题，获得所需的快速设计帮助。

链接的内容由各个贡献者“按原样”提供。这些内容并不构成 TI 技术规范，并且不一定反映 TI 的观点；请参阅 TI 的[使用条款](#)。

9.3 Trademarks

TI E2E™ is a trademark of Texas Instruments.

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9.4 静电放电警告



静电放电 (ESD) 会损坏这个集成电路。德州仪器 (TI) 建议通过适当的预防措施处理所有集成电路。如果不遵守正确的处理和安装程序，可能会损坏集成电路。

ESD 的损坏小至导致微小的性能降级，大至整个器件故障。精密的集成电路可能更容易受到损坏，这是因为非常细微的参数更改都可能会导致器件与其发布的规格不相符。

9.5 术语表

[TI 术语表](#) 本术语表列出并解释了术语、首字母缩略词和定义。

10 Revision History

注：以前版本的页码可能与当前版本的页码不同

Changes from Revision R (October 2023) to Revision S (February 2024)	Page
• Updated thermal values for DBV package from $R_{\theta JA} = 226$ to 278, $R_{\theta JC(top)} = 165$ to 180.5, $R_{\theta JB} = 59.1$ to 184.4, $\Psi_{JT} = 45.5$ to 115.4, $\Psi_{JB} = 58.3$ to 183.4, $R_{\theta JC(bot)} = N/A$, all values in $^{\circ}C/W$	5

Changes from Revision Q (April 2016) to Revision R (October 2023)	Page
• 更新了整个文档中的表、图和交叉参考的编号格式.....	1
• Updated thermal values for DCK package from $R_{\theta JA} = 277.5$ to 289.2, $R_{\theta JC(top)} = 92.9$ to 205.8, $R_{\theta JB} = 64.2$ to 176.2, $\Psi_{JT} = 1.9$ to 117.6, $\Psi_{JB} = 63.5$ to 175.1, $R_{\theta JC(bot)} = N/A$, all values in $^{\circ}C/W$	5

11 Mechanical, Packaging, and Orderable Information

The following pages include mechanical packaging and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser based versions of this data sheet, refer to the left hand navigation.

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
74AHCT1G08DBVRG4	ACTIVE	SOT-23	DBV	5	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	B08G	Samples
74AHCT1G08DRLRG4	ACTIVE	SOT-5X3	DRL	5	4000	RoHS & Green	NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	(BEB, BES)	Samples
SN74AHCT1G08DBV3	ACTIVE	SOT-23	DBV	5	3000	RoHS & Non-Green	SNBI	Level-1-260C-UNLIM	-40 to 125	B08Y	Samples
SN74AHCT1G08DBVR	ACTIVE	SOT-23	DBV	5	3000	RoHS & Green	NIPDAU SN	Level-1-260C-UNLIM	-40 to 125	(B083, B08G, B08J, B08L, B08S)	Samples
SN74AHCT1G08DCK3	ACTIVE	SC70	DCK	5	3000	RoHS & Non-Green	SNBI	Level-1-260C-UNLIM	-40 to 125	BEY	Samples
SN74AHCT1G08DCKR	ACTIVE	SC70	DCK	5	3000	RoHS & Green	NIPDAU SN	Level-1-260C-UNLIM	-40 to 125	(1PJ, BE3, BEG, BE J, BEL, BES)	Samples
SN74AHCT1G08DRLR	ACTIVE	SOT-5X3	DRL	5	4000	RoHS & Green	NIPDAU NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	(BEB, BES)	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

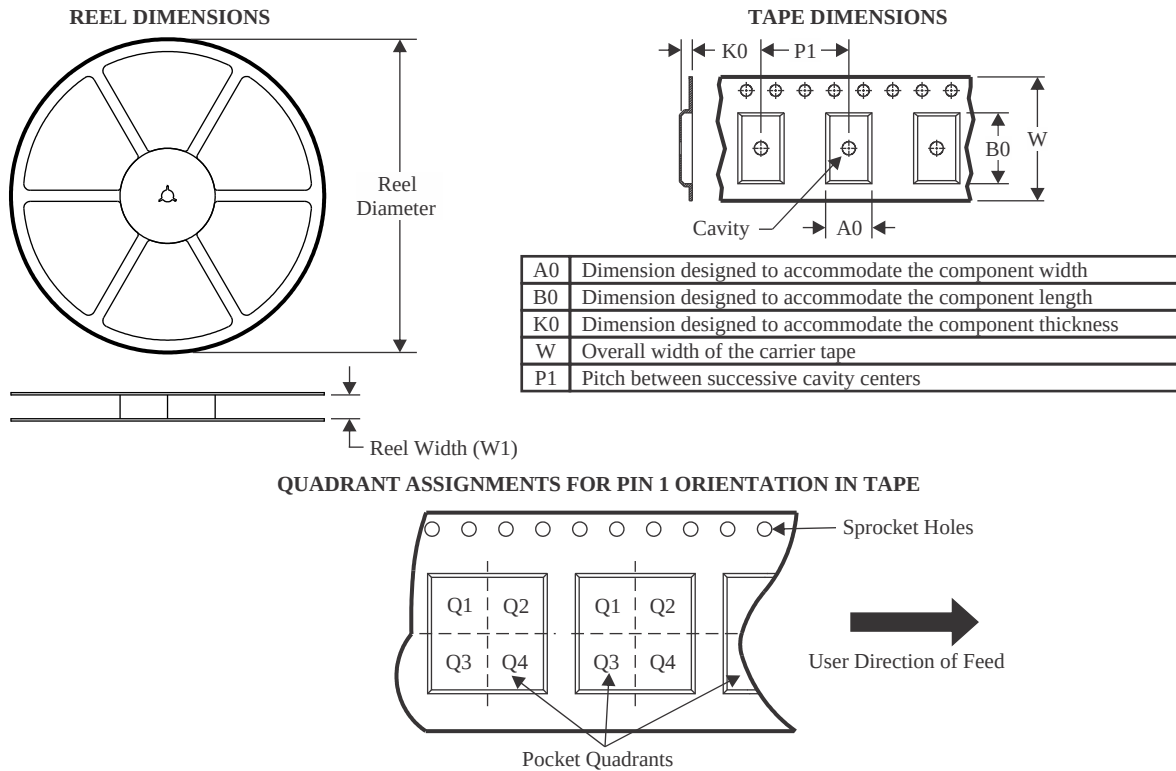
OTHER QUALIFIED VERSIONS OF SN74AHCT1G08 :

- Automotive : [SN74AHCT1G08-Q1](#)

NOTE: Qualified Version Definitions:

- Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects

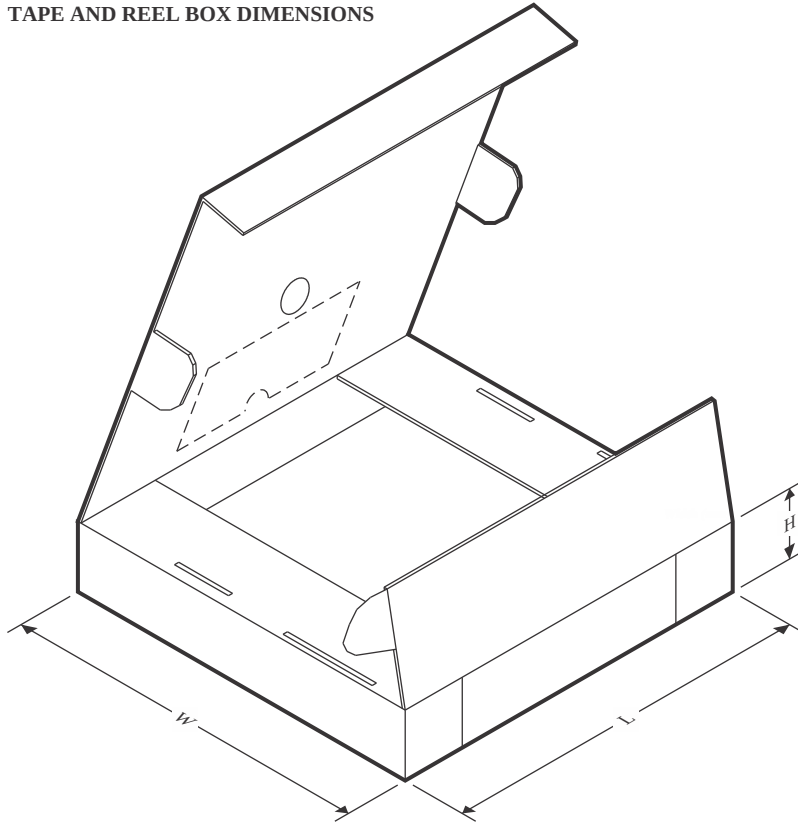
TAPE AND REEL INFORMATION



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
74AHCT1G08DBVRG4	SOT-23	DBV	5	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
SN74AHCT1G08DBVR	SOT-23	DBV	5	3000	180.0	8.4	3.23	3.17	1.37	4.0	8.0	Q3
SN74AHCT1G08DBVR	SOT-23	DBV	5	3000	178.0	9.0	3.3	3.2	1.4	4.0	8.0	Q3
SN74AHCT1G08DCKR	SC70	DCK	5	3000	180.0	8.4	2.3	2.5	1.2	4.0	8.0	Q3
SN74AHCT1G08DRLR	SOT-5X3	DRL	5	4000	180.0	8.4	1.98	1.78	0.69	4.0	8.0	Q3

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
74AHCT1G08DBVRG4	SOT-23	DBV	5	3000	180.0	180.0	18.0
SN74AHCT1G08DBVR	SOT-23	DBV	5	3000	202.0	201.0	28.0
SN74AHCT1G08DBVR	SOT-23	DBV	5	3000	180.0	180.0	18.0
SN74AHCT1G08DCKR	SC70	DCK	5	3000	210.0	185.0	35.0
SN74AHCT1G08DRLR	SOT-5X3	DRL	5	4000	202.0	201.0	28.0



SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



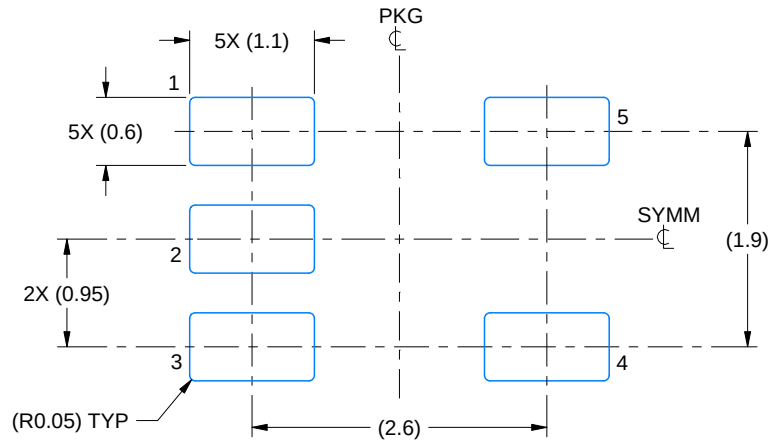
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. Reference JEDEC MO-178.
4. Body dimensions do not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.25 mm per side.
5. Support pin may differ or may not be present.

EXAMPLE BOARD LAYOUT

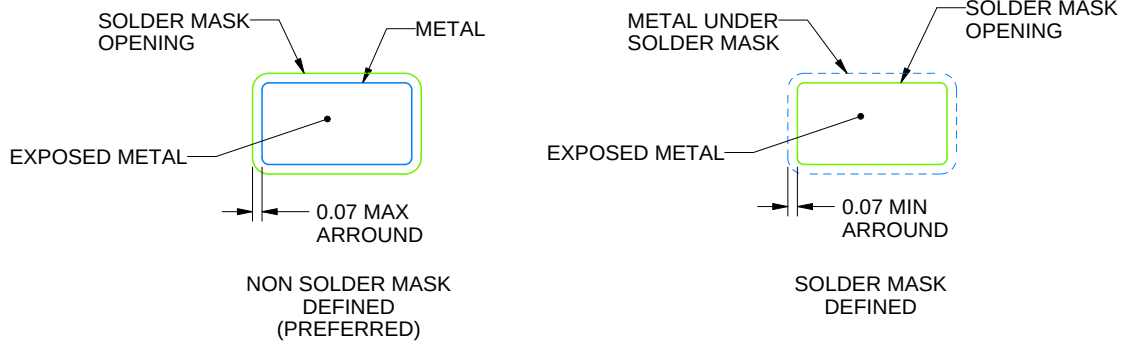
DBV0005A

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:15X



SOLDER MASK DETAILS

4214839/J 02/2024

NOTES: (continued)

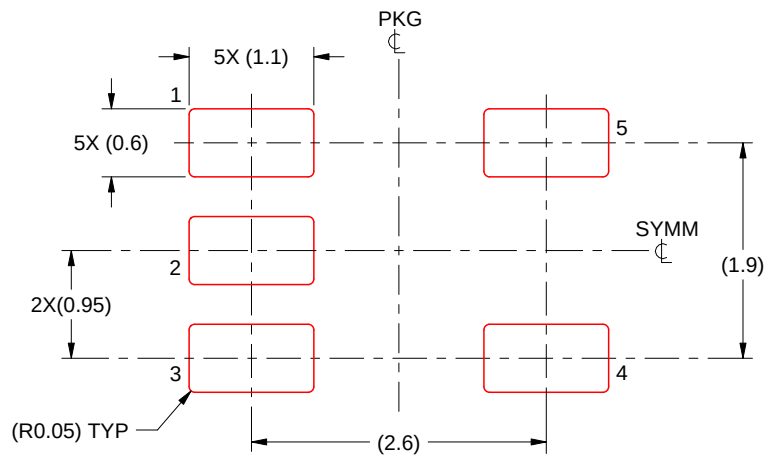
6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

DBV0005A

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR

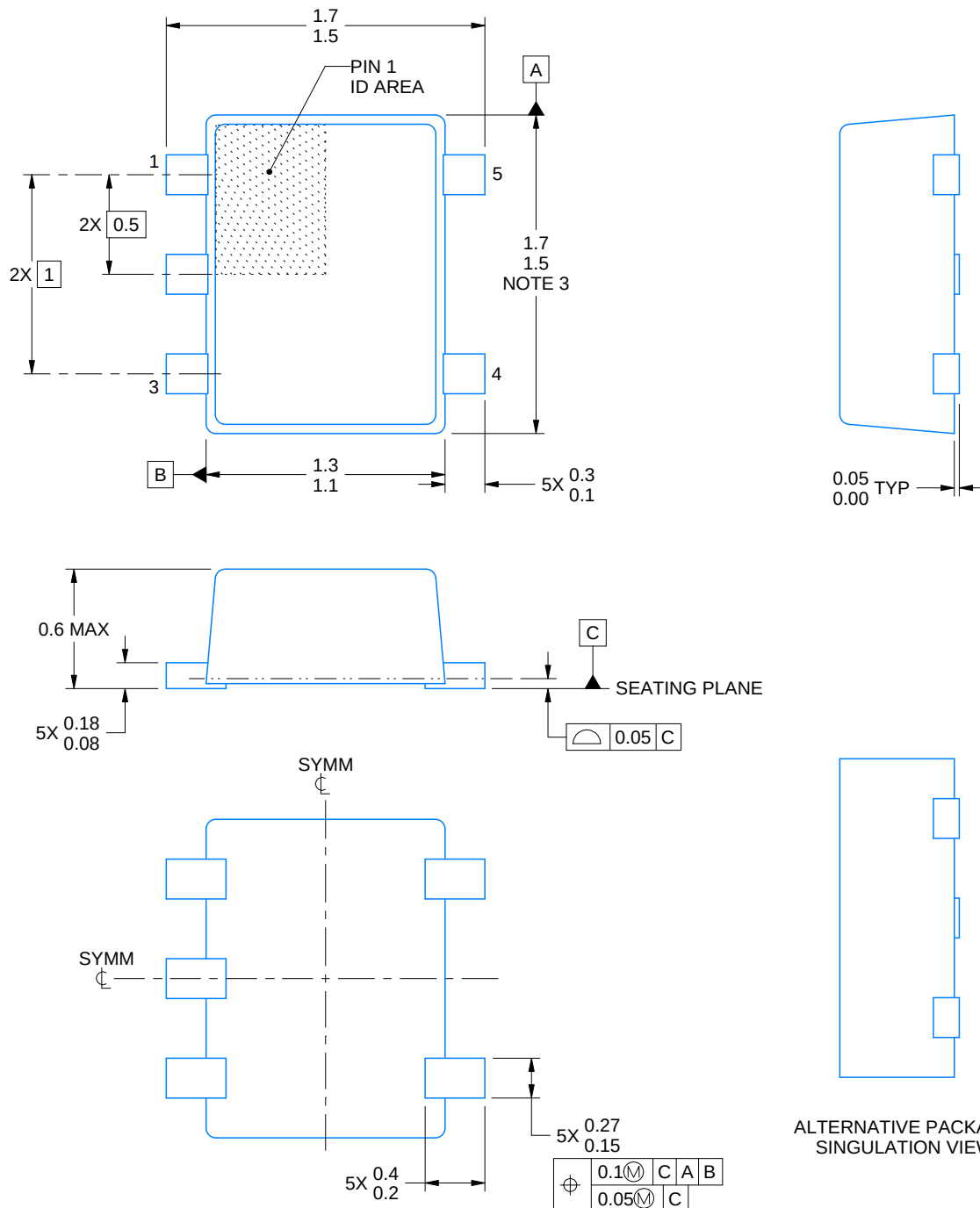
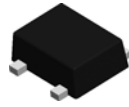


SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:15X

4214839/J 02/2024

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.



4220753/C 04/2024

NOTES:

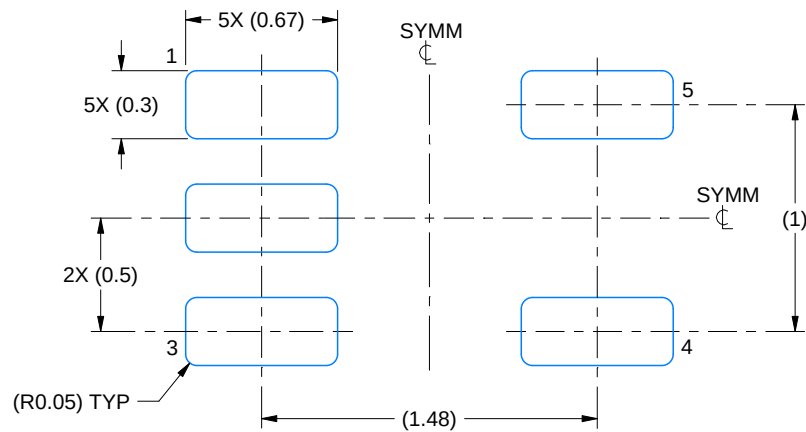
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. Reference JEDEC registration MO-293 Variation UAAD-1

EXAMPLE BOARD LAYOUT

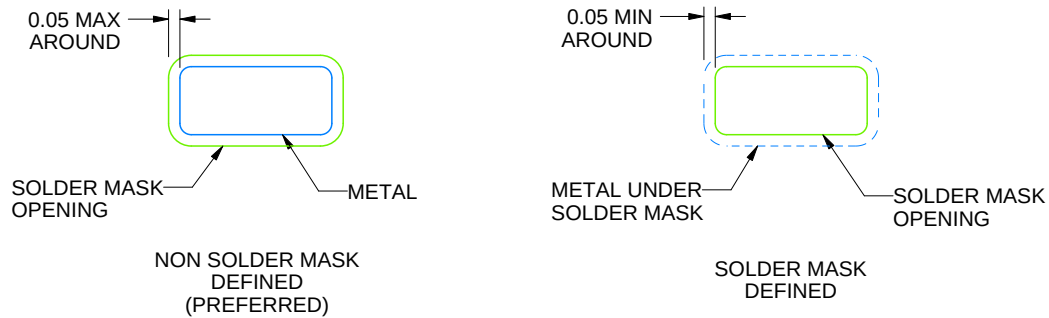
DRL0005A

SOT - 0.6 mm max height

PLASTIC SMALL OUTLINE



LAND PATTERN EXAMPLE
SCALE:30X



SOLDERMASK DETAILS

4220753/C 04/2024

NOTES: (continued)

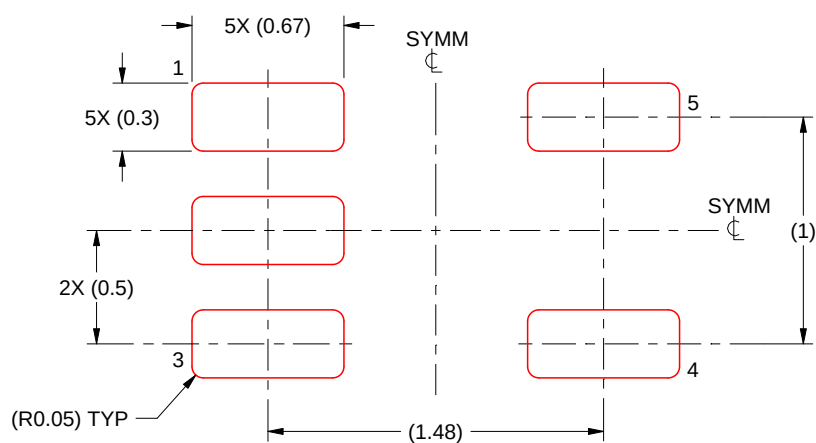
5. Publication IPC-7351 may have alternate designs.
6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

DRL0005A

SOT - 0.6 mm max height

PLASTIC SMALL OUTLINE

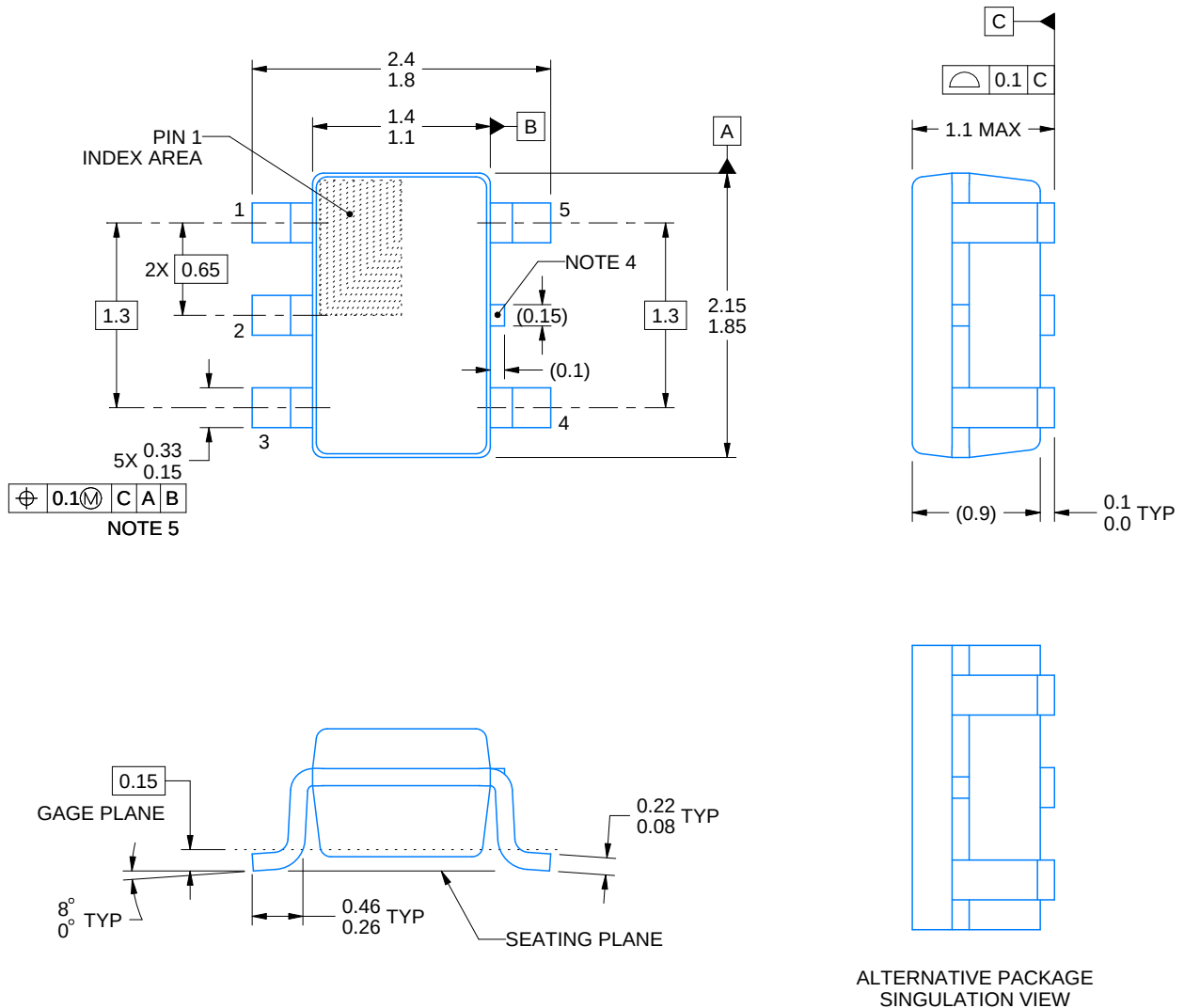


SOLDER PASTE EXAMPLE
BASED ON 0.1 mm THICK STENCIL
SCALE:30X

4220753/C 04/2024

NOTES: (continued)

7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
8. Board assembly site may have different recommendations for stencil design.



4214834/E 06/2024

NOTES:

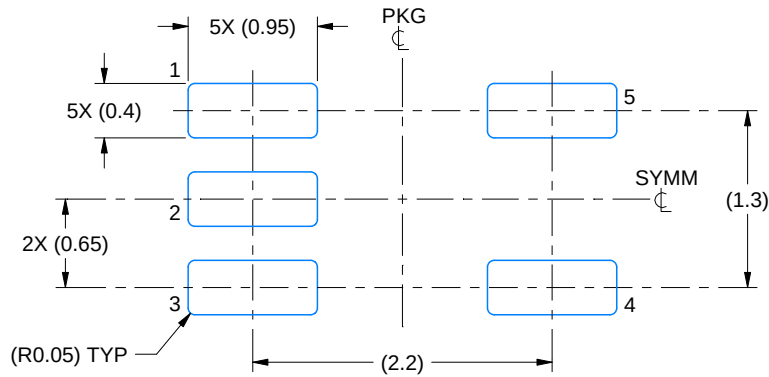
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. Reference JEDEC MO-203.
4. Support pin may differ or may not be present.
5. Lead width does not comply with JEDEC.
6. Body dimensions do not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.25mm per side

EXAMPLE BOARD LAYOUT

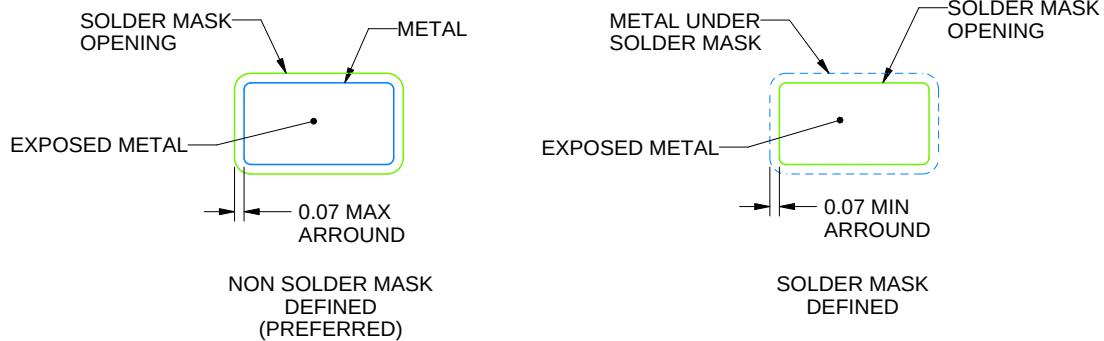
DCK0005A

SOT - 1.1 max height

SMALL OUTLINE TRANSISTOR



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:18X

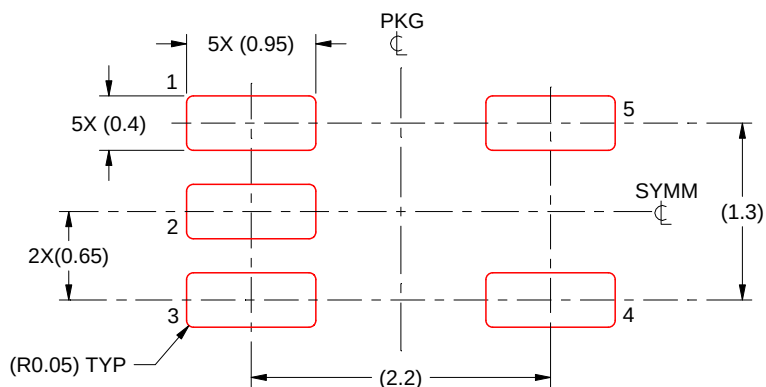


SOLDER MASK DETAILS

4214834/E 06/2024

NOTES: (continued)

7. Publication IPC-7351 may have alternate designs.
8. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOLDER PASTE EXAMPLE
BASED ON 0.125 THICK STENCIL
SCALE:18X

4214834/E 06/2024

NOTES: (continued)

9. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
10. Board assembly site may have different recommendations for stencil design.

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